

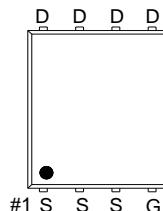
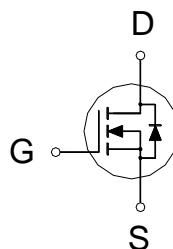
NIKO-SEM
**N-Channel Enhancement Mode
Field Effect Transistor**
PP1515AK

PDFN 5X6P

Halogen-Free & Lead-Free

PRODUCT SUMMARY

$V_{(BR)DSS}$	$R_{DS(ON)}$	I_D
150V	15mΩ	44A


 G. GATE
 D. DRAIN
 S. SOURCE
ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Drain-Source Voltage		V_{DS}	150	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current	$T_C = 25^\circ\text{C}$	I_D	44	A
	$T_C = 100^\circ\text{C}$		28	
Pulsed Drain Current ¹		I_{DM}	112	
Continuous Drain Current	$T_A = 25^\circ\text{C}$	I_D	9.2	
	$T_A = 70^\circ\text{C}$		7.4	
Avalanche Current		I_{AS}	16	
Avalanche Energy	$L = 1\text{mH}$	E_{AS}	128	mJ
Power Dissipation	$T_C = 25^\circ\text{C}$	P_D	63	W
	$T_C = 100^\circ\text{C}$		25	
Power Dissipation ³	$T_A = 25^\circ\text{C}$	P_D	2.8	W
	$T_A = 70^\circ\text{C}$		1.8	
Operating Junction & Storage Temperature Range		T_j, T_{stg}	-55 to 150	°C

THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE		SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Ambient ²	$t \leq 10\text{s}$	$R_{\theta JA}$		45	°C / W
Junction-to-Ambient ²	Steady-State	$R_{\theta JA}$		74	
Junction-to-Case	Steady-State	$R_{\theta JC}$		2	

¹Pulse width limited by maximum junction temperature.²The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.³The Power dissipation is based on $R_{\theta JA}$ $t \leq 10\text{s}$ value.

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ELECTRICAL CHARACTERISTICS (T_J = 25 ° C, Unless Otherwise Noted)

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 250μA	150			V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250μA	2	2.9	4	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0V, V _{GS} = ±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 150V, V _{GS} = 0V			1	μA
		V _{DS} = 120V, V _{GS} = 0V, T _J = 55 ° C			10	
Drain-Source On-State Resistance ¹	R _{DS(ON)}	V _{GS} = 10V, I _D = 20A		11	15	mΩ
Forward Transconductance ¹	g _{fs}	V _{DS} = 5V, I _D = 20A		54		S
DYNAMIC						
Input Capacitance	C _{iss}	V _{GS} = 0V, V _{DS} = 75V, f = 1MHz		2599		pF
Output Capacitance	C _{oss}			240		
Reverse Transfer Capacitance	C _{rss}			5.5		
Total Gate Charge ²	Q _g	V _{GS} = 10V , V _{DS} = 75V I _D = 20A		37		nC
Gate-Source Charge ²	Q _{gs}			12		
Gate-Drain Charge ²	Q _{gd}			8.8		
Turn-On Delay Time ²	t _{d(on)}	V _{DS} = 75V , I _D ≈ 20A, V _{GS} = 10V, R _{GEN} = 6Ω		19		nS
Rise Time ²	t _r			64		
Turn-Off Delay Time ²	t _{d(off)}			35		
Fall Time ²	t _f			79		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (T_J = 25 ° C)						
Continuous Current	I _S	I _F = 20A, dl/dt=100A/μs			44	A
Forward Voltage ¹	V _{SD}				1.2	V
Diode Reverse Recovery Time	t _{rr}			91		nS
Diode Reverse Recovery Charge	Q _{rr}			208		nC

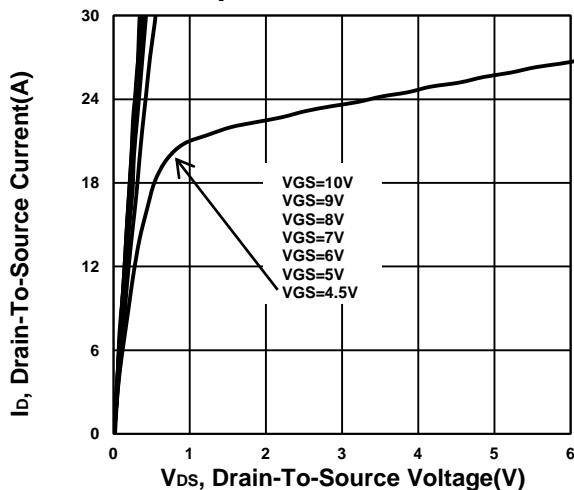
¹Pulse test : Pulse Width ≤ 300 μsec, Duty Cycle ≤ 2%.²Independent of operating temperature.

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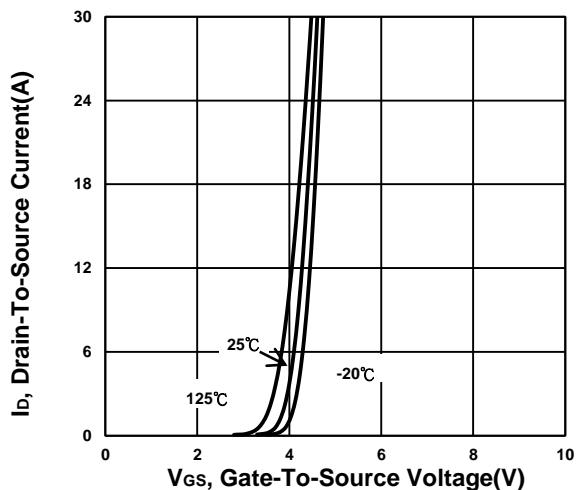
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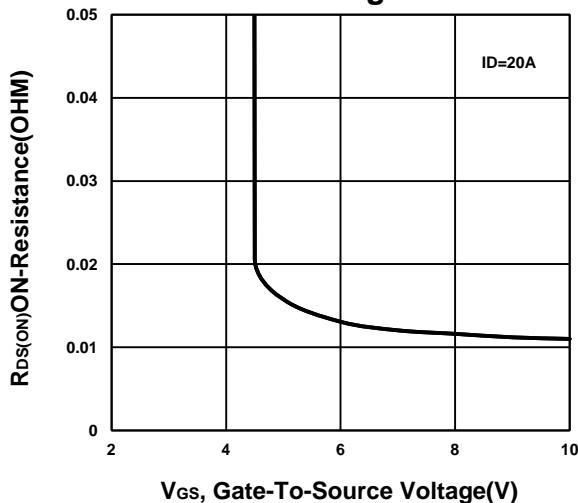
Output Characteristics



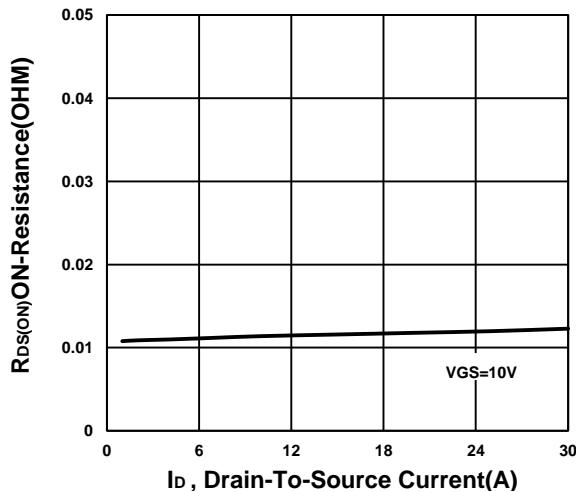
Transfer Characteristics



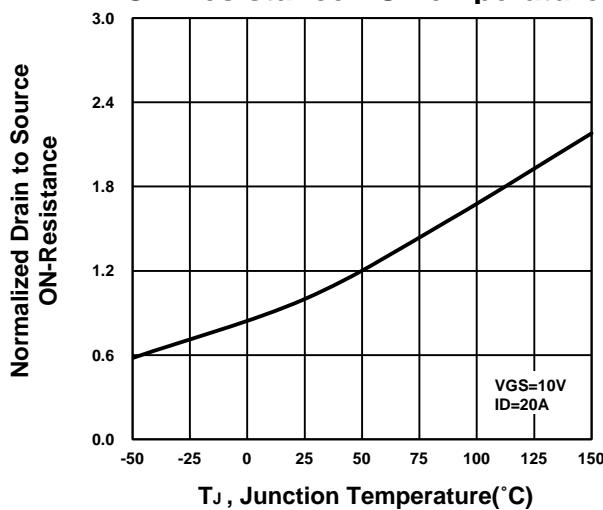
On-Resistance VS Gate-to-Source Voltage



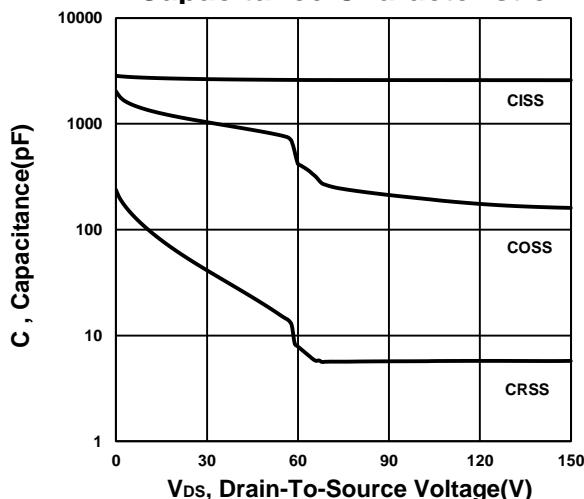
On-Resistance VS Drain Current

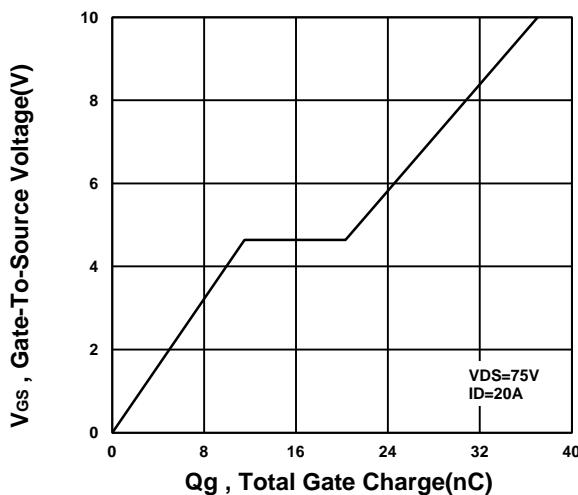
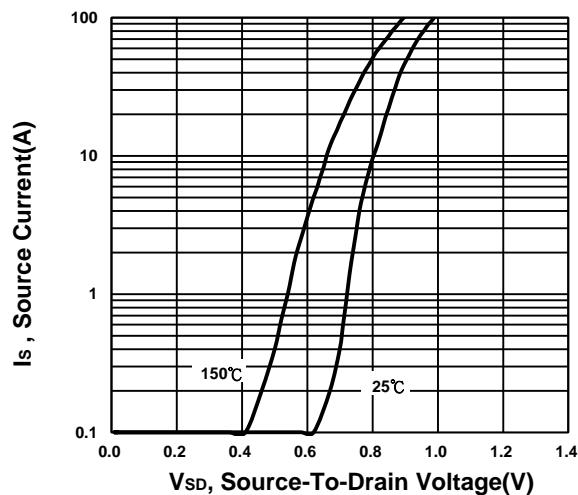
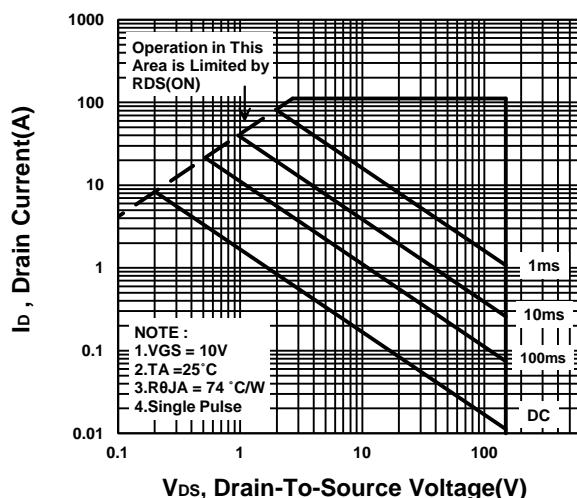
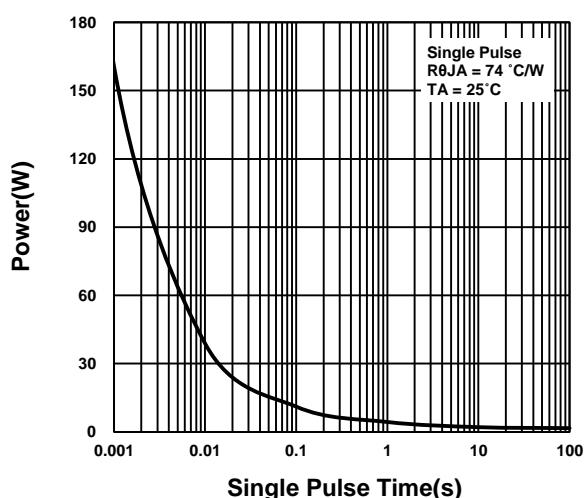
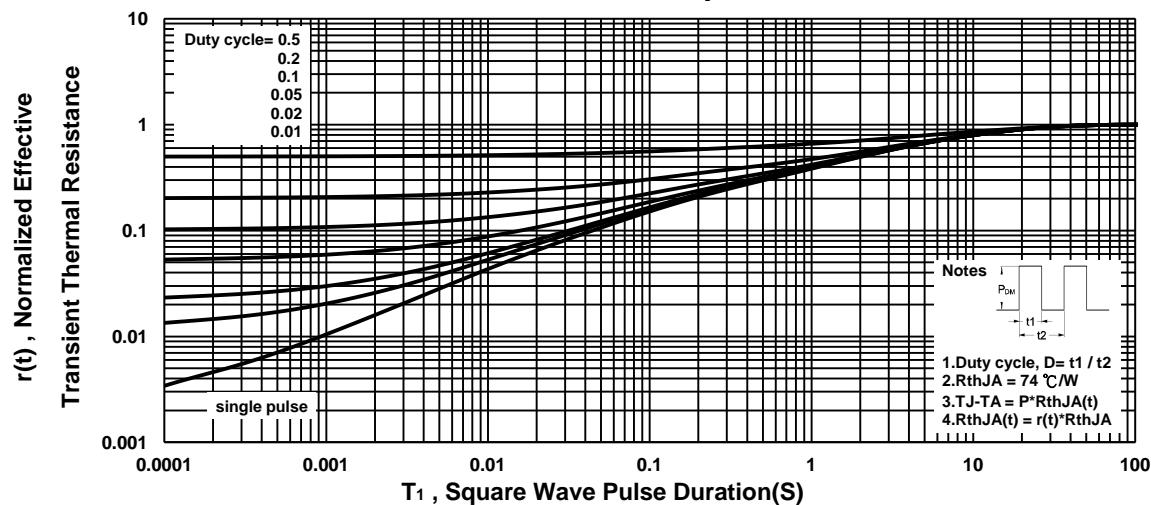


On-Resistance VS Temperature



Capacitance Characteristic



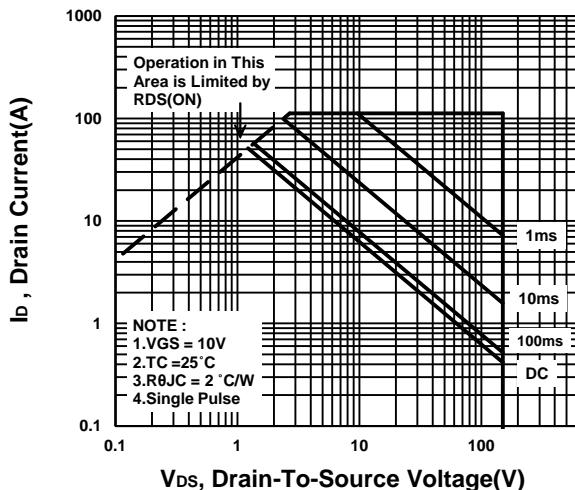
NIKO-SEM**N-Channel Enhancement Mode
Field Effect Transistor****PP1515AK
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Halogen-Free & Lead-Free****Gate charge Characteristics****Source-Drain Diode Forward Voltage****Safe Operating Area****Single Pulse Maximum Power Dissipation****Transient Thermal Response Curve**

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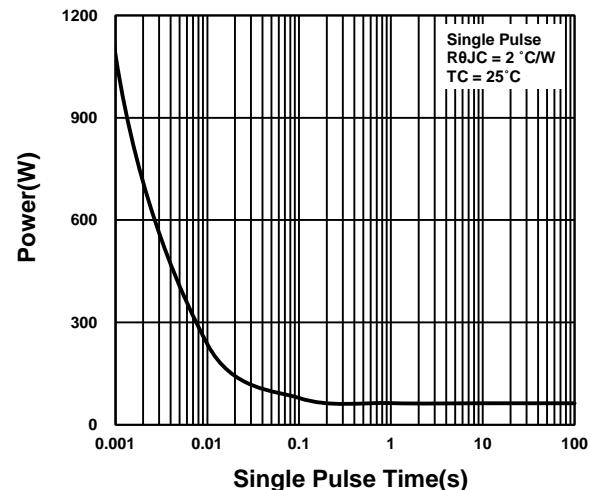
**N-Channel Enhancement Mode
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Safe Operating Area



Single Pulse Maximum Power Dissipation



Transient Thermal Response Curve

